

TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

# TC75S103F

Single Operational Amplifier

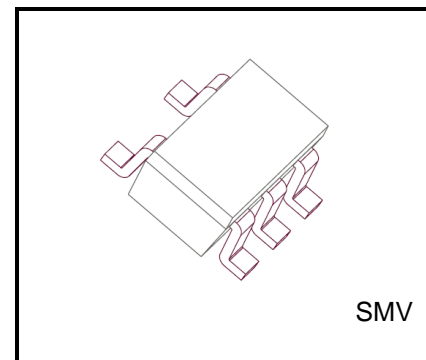
Low supply current

## Features

- Input, Output Full Range type (Rail to Rail)
- Low supply current 100 $\mu$ A (Typ.) @ $V_{DD}=1.8V$
- Low Input offset voltage 1.5mV (Max) @ $V_{DD}=1.8V$
- Wide Operating Voltage Range 1.8V to 5.5V

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{DD} - V_{SS}$	6	V
Differential input voltage	$DV_{IN}$	$\pm 6$	V
Input voltage	$V_{IN}$	$V_{DD}$ to $V_{SS}$	V
Output voltage	$V_{OUT}$	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V \leq V_{SS} + 6V$	V
Output current	$I_{OUT}$	$\pm 25$	mA
Power dissipation	$P_D$	200	mW
Operating temperature	$T_{opr}$	-40 to 105	°C
Storage temperature	$T_{stg}$	-55 to 150	°C



Weight:

SMV (SOT-25)(SC-74A) :14 mg (typ.)

Note1: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Operating Ratings (Ta = -40 to 105°C)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{DD} - V_{SS}$	1.8 to 5.5	V

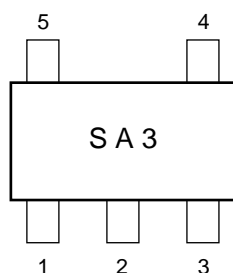
Note2: A higher load capacitance will increase the risk of voltage oscillation. Allow sufficient capacitance value when designing your circuit and using this product to prevent voltage oscillation.

Note3: This device is sensitive to electrostatic discharge.

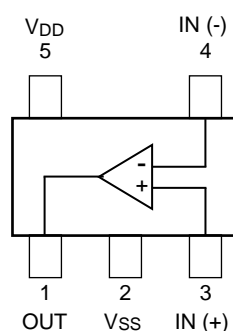
Please ensure equipment, operator and tools are adequately earthed when handling.

Start of commercial production  
2020-09

Marking (top view)



Pin Assignment (top view)



## Electrical Characteristics

**DC Characteristics ( $V_{DD} = 1.8V$ ,  $V_{SS} = GND$ ,  $T_a = 25^\circ C$ ,  $V_{IN} = V_{DD}/2$ , unless otherwise noted.)**

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	$V_{IO}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = -40\text{ to }105^\circ C$	-1.85	0.3	1.85	mV
			$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = 25^\circ C$	-1.5	0.3	1.5	mV
Input offset voltage drift	$V_{IO\text{drift}}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	-	1	-	$\mu V/^\circ C$
Input offset current	$I_{IO}$	2	-	-	1	-	pA
Input bias current	$I_I$	2	-	-	1	-	pA
Common mode input voltage	$CMV_{IN}$	3	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	0	-	$V_{DD}$	V
Voltage gain (open loop)	$G_V$	-	-	85	100	-	dB
Maximum output voltage	$V_{OH}$	4	$R_L \geq 100\text{ k}\Omega$	1.7	-	-	V
	$V_{OL}$	5	$R_L \geq 100\text{ k}\Omega$	-	-	0.1	
Common mode input signal rejection ratio	$CMRR$	3	$V_{IN} = 0\text{ to }1.8V$	60	80	-	dB
Supply voltage rejection ratio	$SVRR$	1	$V_{DD} = 1.8\text{ to }5.0V$	70	85	-	dB
Supply current	$I_{DD}$	6	-	-	100	165	$\mu A$
Source current	$I_{\text{source}}$	7	-	1.2	2	-	mA
Sink current	$I_{\text{sink}}$	8	-	1	2	-	mA

**AC Characteristics ( $V_{DD} = 0.9\text{ V}$ ,  $V_{SS} = -0.9\text{ V}$ ,  $T_a = 25^\circ C$ )**

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Unity Gain Cross Frequency	$f_T$	-	-	-	0.3	-	MHz
Phase margin	$\Phi_m$	-	-	-	40	-	degrees
Slew Rate	$SR$	-	-	-	0.52	-	V/ $\mu s$

### DC Characteristics ( $V_{DD} = 3.3V$ , $V_{SS} = GND$ , $T_a = 25^\circ C$ , $V_{IN} = V_{DD}/2$ , unless otherwise noted.)

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	$V_{IO}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = -40\text{ to }105^\circ C$	-2.15	0.4	2.15	mV
			$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = 25^\circ C$	-1.85	0.4	1.85	mV
Input offset voltage drift	$V_{IO\text{drift}}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	-	2	-	$\mu V/^\circ C$
Input offset current	$I_{IO}$	2	-	-	1	-	pA
Input bias current	$I_I$	2	-	-	1	-	pA
Common mode input voltage	$CMV_{IN}$	3	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	0	-	$V_{DD}$	V
Voltage gain (open loop)	$G_V$	-	-	100	125	-	dB
Maximum output voltage	$V_{OH}$	4	$R_L \geq 100\text{ k}\Omega$	3.2	-	-	V
	$V_{OL}$	5	$R_L \geq 100\text{ k}\Omega$	-	-	0.1	
Common mode input signal rejection ratio	$CMRR$	3	$V_{IN} = 0\text{ to }3.3V$	65	90	-	dB
Supply current	$I_{DD}$	6	-	-	100	165	$\mu A$
Source current	$I_{\text{source}}$	7	-	6	10	-	mA
Sink current	$I_{\text{sink}}$	8	-	6	10	-	mA

### AC Characteristics ( $V_{DD} = 1.65\text{ V}$ , $V_{SS} = -1.65\text{ V}$ , $T_a = 25^\circ C$ )

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Unity Gain Cross Frequency	$f_T$	-	-	-	0.36	-	MHz
Phase margin	$\Phi_m$	-	-	-	60	-	degrees
Slew Rate	$SR$	-	-	-	0.4	-	V/ $\mu s$

**DC Characteristics ( $V_{DD} = 5.0V$ ,  $V_{SS} = GND$ ,  $T_a = 25^\circ C$ ,  $V_{IN} = V_{DD}/2$ , unless otherwise noted.)**

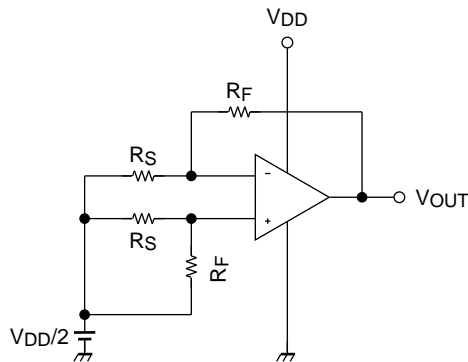
Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input offset voltage	$V_{IO}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = -40\text{ to }105^\circ C$	-2.15	0.4	2.15	mV
			$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$ $T_a = 25^\circ C$	-1.85	0.4	1.85	mV
Input offset voltage drift	$V_{IO\text{drift}}$	1	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	-	2	-	$\mu V/^\circ C$
Input offset current	$I_{IO}$	2	-	-	1	-	pA
Input bias current	$I_I$	2	-	-	1	-	pA
Common mode input voltage	$CMV_{IN}$	3	$R_S = 1\text{ k}\Omega$ , $R_F = 100\text{ k}\Omega$	0	-	$V_{DD}$	V
Voltage gain (open loop)	$G_V$	-	-	100	125	-	dB
Maximum output voltage	$V_{OH}$	4	$R_L \geq 100\text{ k}\Omega$	4.9	-	-	V
	$V_{OL}$	5	$R_L \geq 100\text{ k}\Omega$	-	-	0.1	
Common mode input signal rejection ratio	$CMRR$	3	$V_{IN} = 0\text{ to }5.0V$	68	90	-	dB
Supply current	$I_{DD}$	6	-	-	115	190	$\mu A$
Source current	$I_{\text{source}}$	7	-	17	-	-	mA
Sink current	$I_{\text{sink}}$	8	-	17	-	-	mA

**AC Characteristics ( $V_{DD} = 2.5\text{ V}$ ,  $V_{SS} = -2.5\text{ V}$ ,  $T_a = 25^\circ C$ )**

Characteristics	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Unity Gain Cross Frequency	$f_T$	-	-	-	0.37	-	MHz
Phase margin	$\Phi_m$	-	-	-	60	-	degrees
Slew Rate	SR	-	-	-	0.4	-	V/ $\mu s$

## Test Circuit

### 1. SVRR, V<sub>IO</sub>



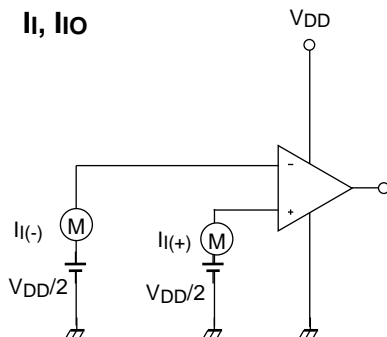
- SVRR
- For each of the two  $V_{DD}$  values, measure the  $V_{OUT}$  value, as indicated below, and calculate the value of SVRR using the equation shown.  
When  $V_{DD} = 1.8\text{ V}$ ,  $V_{DD} = V_{DD1}$  and  $V_{OUT} = V_{OUT1}$   
When  $V_{DD} = 5.0\text{ V}$ ,  $V_{DD} = V_{DD2}$  and  $V_{OUT} = V_{OUT2}$

$$SVRR = 20 \log \left[ \left| \frac{V_{DD1} - V_{DD2}}{\left\{ V_{OUT1} - \left( \frac{V_{DD1}}{2} \right) \right\} - \left\{ V_{OUT2} - \left( \frac{V_{DD2}}{2} \right) \right\}} \right| \times \frac{R_F + R_S}{R_S} \right]$$

- $V_{IO}$   
Measure the value of  $V_{OUT}$  and calculate the value of  $V_{IO}$  using the following equation.

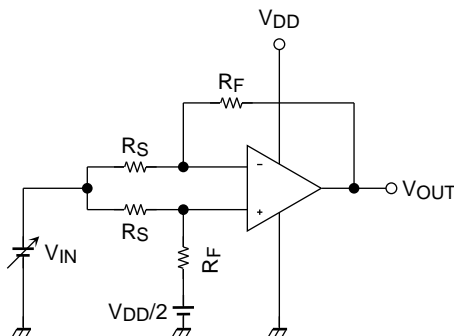
$$V_{IO} = \left( V_{OUT} - \frac{V_{DD}}{2} \right) \times \frac{R_S}{R_F + R_S}$$

### 2. I<sub>I</sub>, I<sub>IO</sub>



- $I_I = (|I_{I(-)}| + |I_{I(+)}|) / 2$
- $I_{IO} = |I_{I(-)}| - |I_{I(+)}|$

### 3. CMRR, CMV<sub>IN</sub>

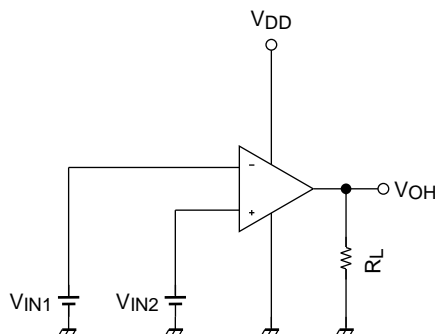


- CMRR  
Measure the  $V_{OUT}$  value, as indicated below, and calculate the value of the CMRR using the equation shown.  
When  $V_{IN} = 0\text{ V}$ ,  $V_{IN} = V_{IN1}$  and  $V_{OUT} = V_{OUT1}$   
When  $V_{IN} = 3.3\text{ V}$ ,  $V_{IN} = V_{IN2}$  and  $V_{OUT} = V_{OUT2}$

$$CMRR = 20 \log \left( \left| \frac{V_{IN1} - V_{IN2}}{V_{OUT1} - V_{OUT2}} \right| \times \frac{R_F + R_S}{R_S} \right)$$

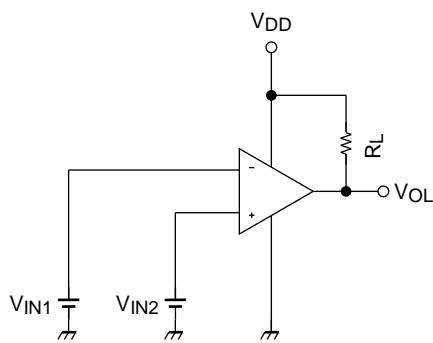
- CMV<sub>IN</sub>  
Input range within which the CMRR specification guarantees  $V_{OUT}$  value (as varied by the  $V_{IN}$  value).

### 4. V<sub>OH</sub>



- $V_{OH}$   
 $V_{IN1} = \frac{V_{DD}}{2} - 0.05\text{ V}$   
 $V_{IN2} = \frac{V_{DD}}{2} + 0.05\text{ V}$

## 5. $V_{OL}$

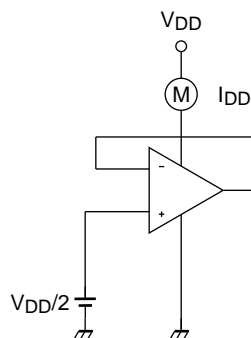


- $V_{OL}$   

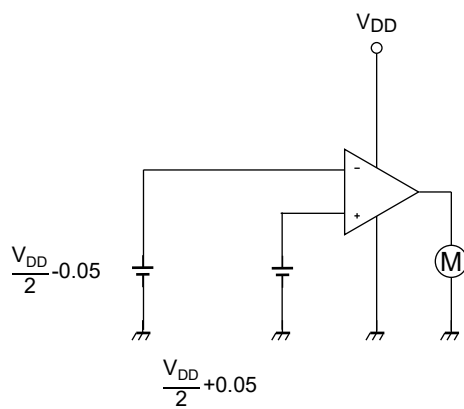
$$V_{IN1} = \frac{V_{DD}}{2} + 0.05V$$

$$V_{IN2} = \frac{V_{DD}}{2} - 0.05V$$

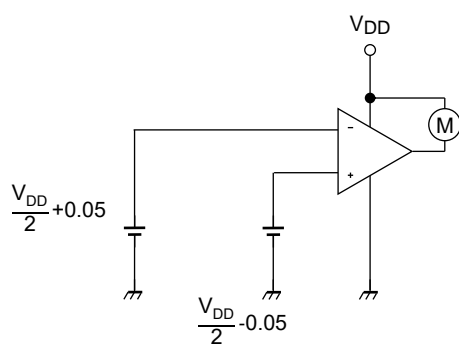
## 6. $I_{DD}$



## 7. $I_{source}$



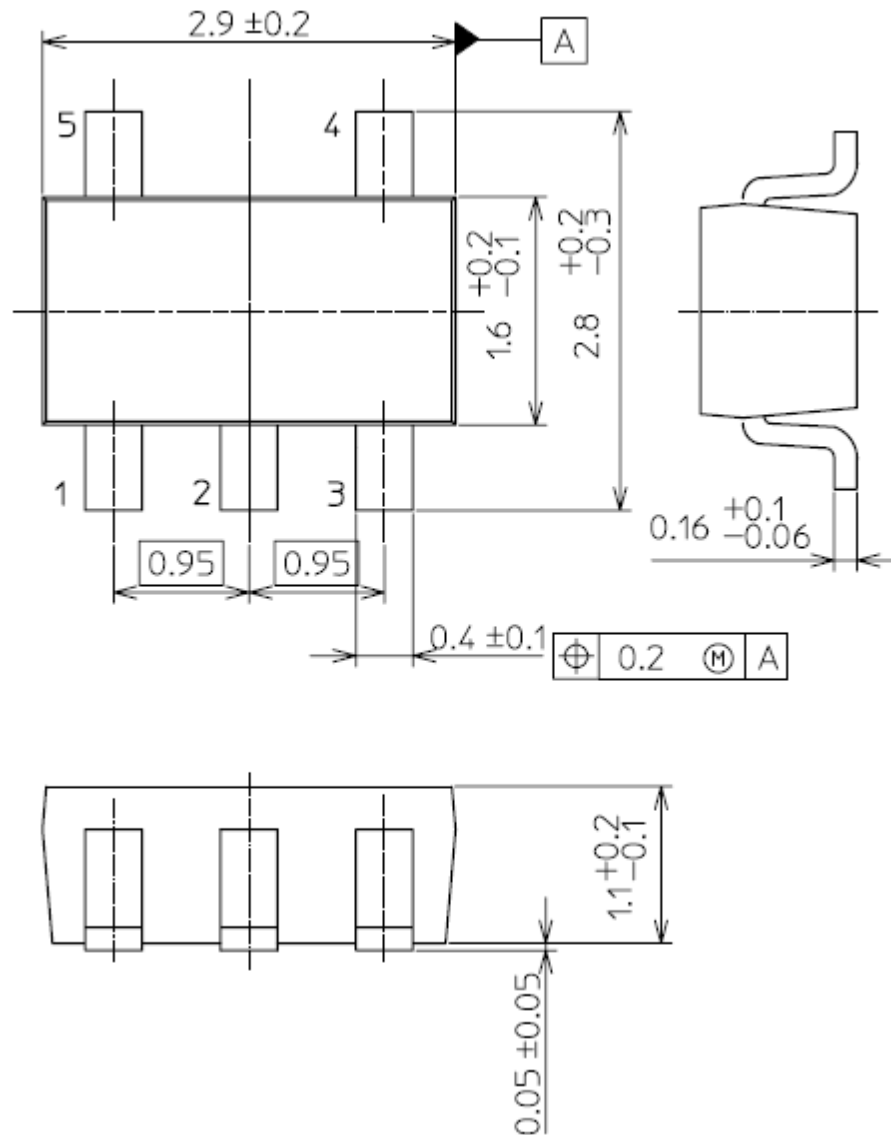
## 8. $I_{sink}$



## Package Dimensions

SMV (SOT-25)(SC-74A)

Unit: mm



Weight : 14 mg ( typ.)

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